



2SA2012/2SC5565

DC/DC Converter Applications

Applications

- Relay drivers, lamp drivers, motor drivers, strobes.

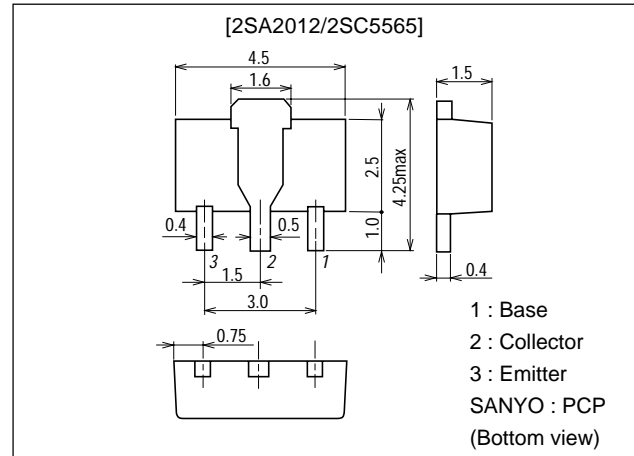
Features

- Adoption of MBIT processes.
- Large current capacitance.
- Low collector-to-emitter saturation voltage.
- Ultrasmall-sized package permitting applied sets to be made small and slim.
- High allowable power dissipation.

Package Dimensions

unit:mm

2038A



Specifications

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Absolute Maximum Ratings at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CBO}		(-30)40	V
Collector-to-Emitter Voltage	V_{CEO}		(-30)	V
Emitter-to-Base Voltage	V_{EBO}		(-5)	V
Collector Current	I_C		(-5)	A
Collector Current (Pulse)	I_{CP}		(-8)	A
Base Current	I_B		(-600)	mA
Collector Dissipation	P_C	Mounted on a ceramic board (250mm ² ×0.8mm)	1.3	W
		$T_c=25^\circ\text{C}$	3.5	W
Junction Temperature	T_j		150	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

Electrical Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB}=(-)30\text{V}, I_E=0$			(-)0.1	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=(-)4\text{V}, I_C=0$			(-)0.1	μA
DC Current Gain	h_{FE}	$V_{CE}=(-)2\text{V}, I_C=(-)500\text{mA}$	200		560	
Gain-Bandwidth Product	f_T	$V_{CE}=(-)10\text{V}, I_C=(-)500\text{mA}$		(350)		MHz
				420		MHz
Output Capacitance	C_{ob}	$V_{CB}=(-)10\text{V}, f=1\text{MHz}$		(30)20		pF

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Marking : 2SA2012 : AS 2SC5565 : FB

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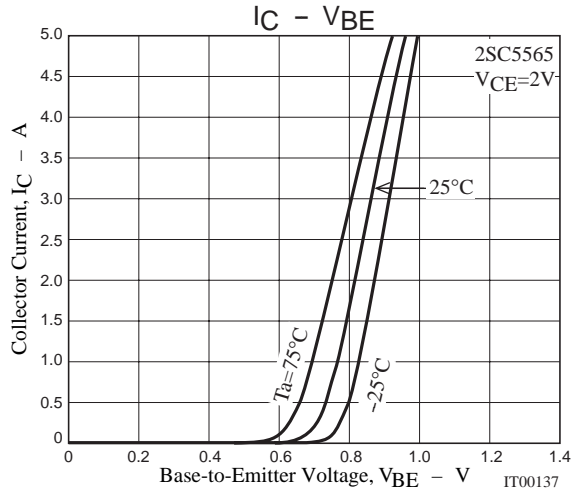
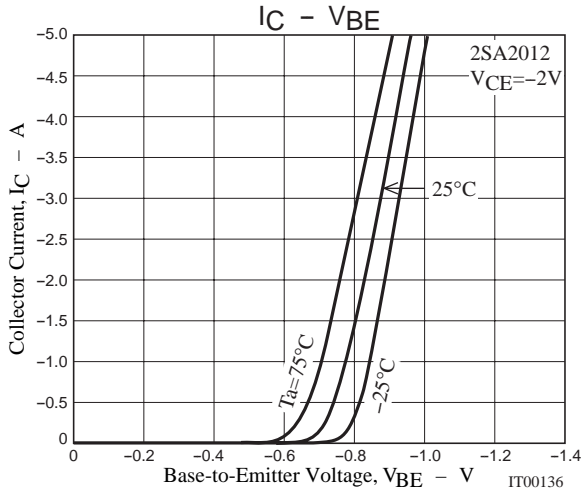
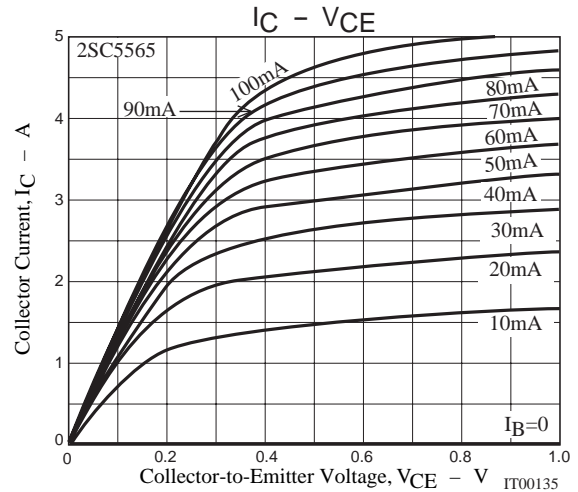
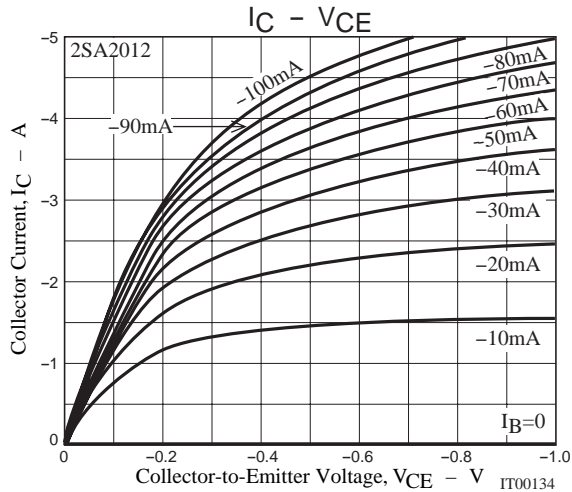
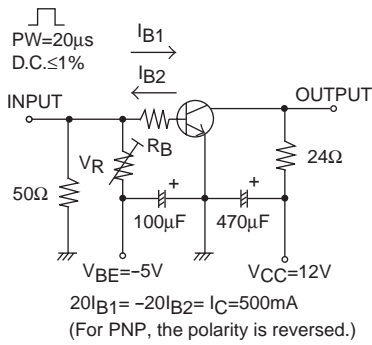
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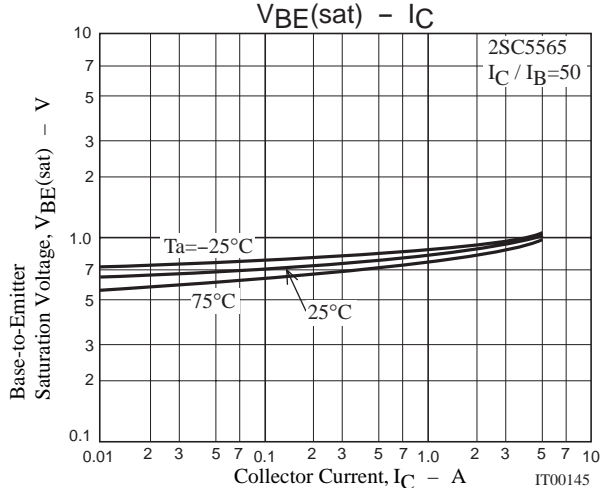
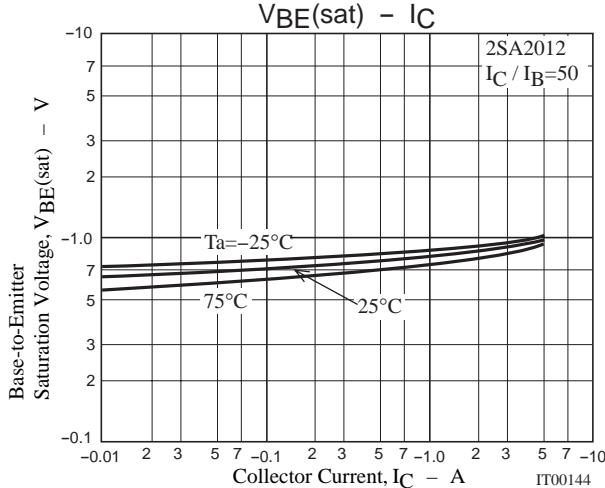
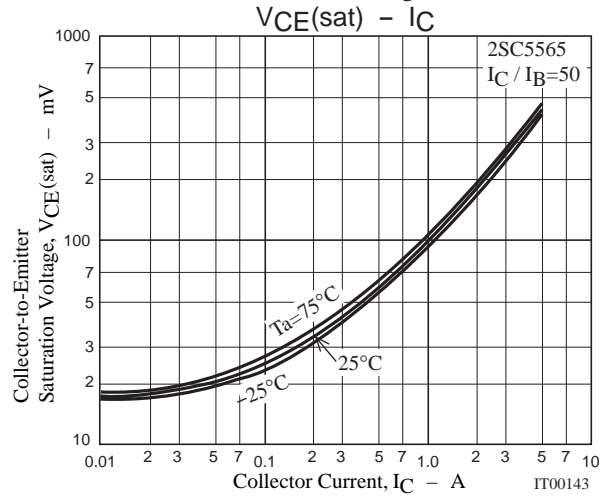
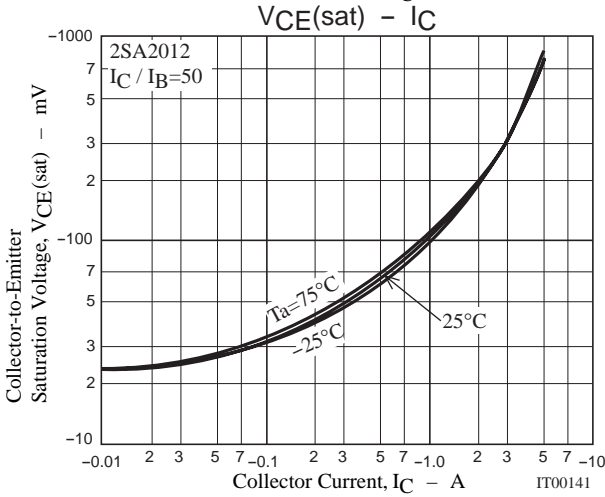
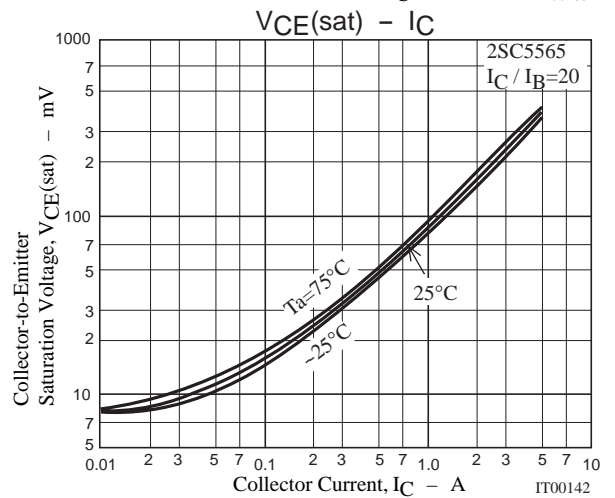
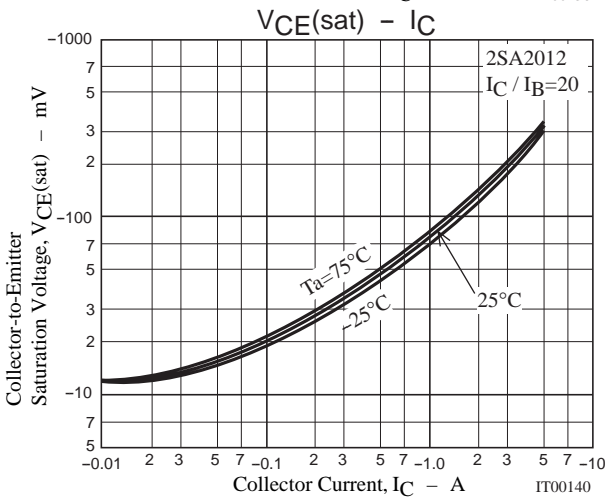
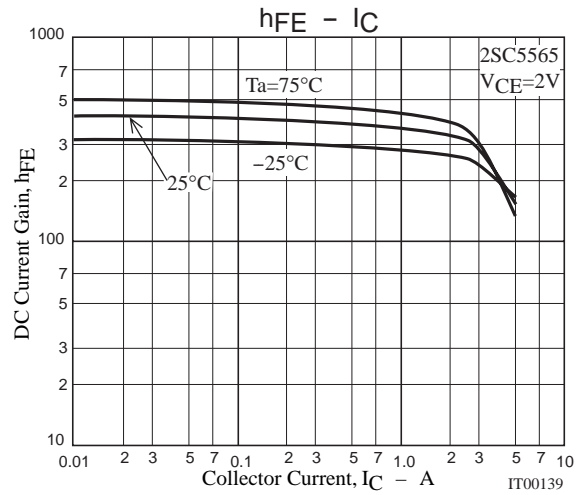
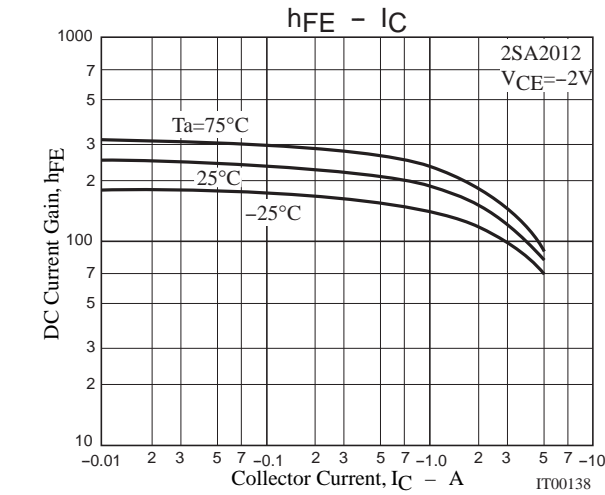
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=(-)1.5A, I_B=(-)30mA$		(-140)	(-210)	mV
				125	190	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=(-)1.5A, I_B=(-)30mA$		(-170)	(-260)	mV
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=(-)10\mu A, I_E=0$	(-30)			V
Collector-to-Base Breakdown Voltage	$V_{(BR)CEO}$	$I_C=(-)1mA, R_{BE}=\infty$	(-30)			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=(-)10\mu A, I_C=0$	(-5)			V
Turn-ON Time	t_{on}	See specified Test Circuit		(50)30		ns
Storage Time	t_{stg}	See specified Test Circuit		(270)		ns
				300		ns
Fall Time	t_f	See specified Test Circuit		(25)15		ns

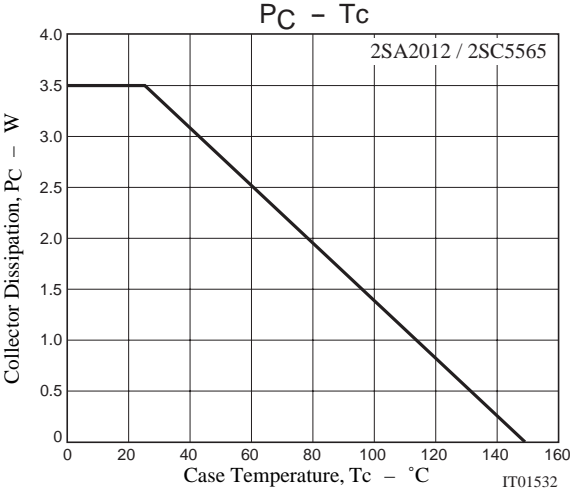
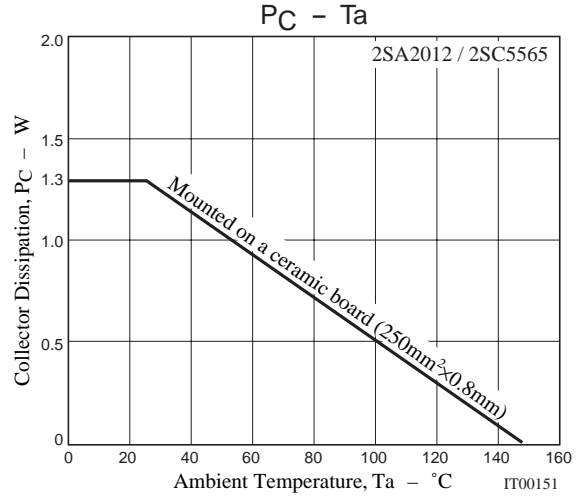
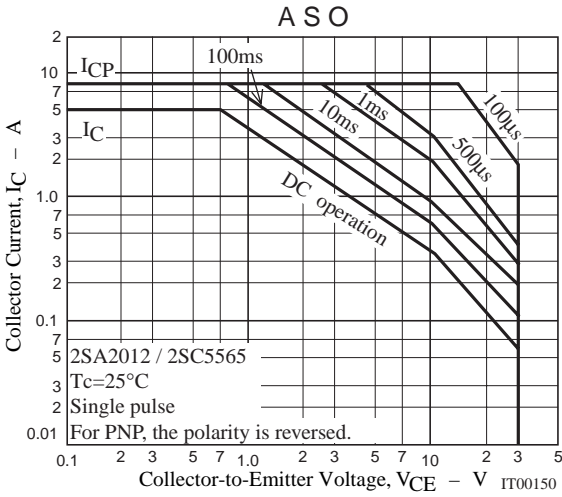
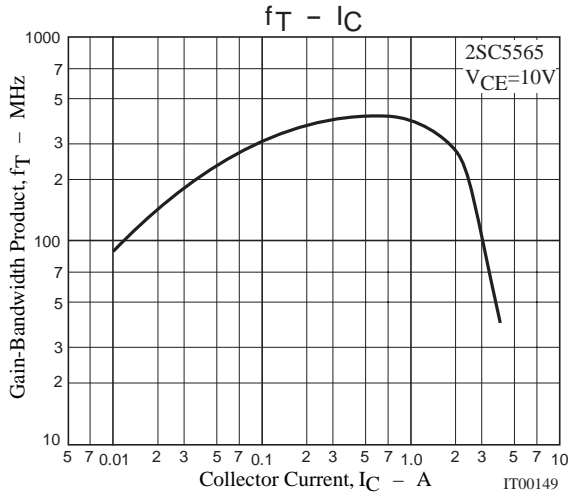
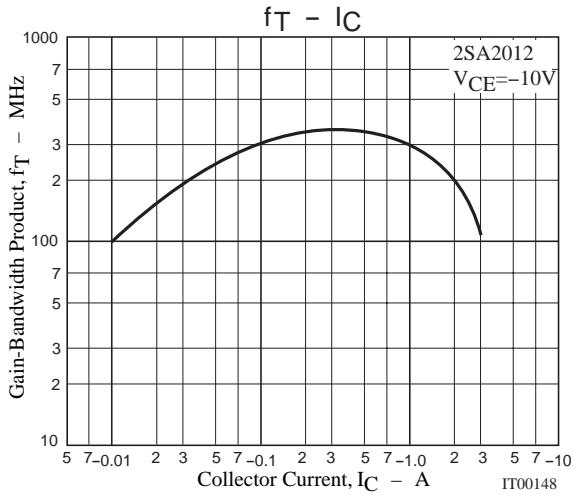
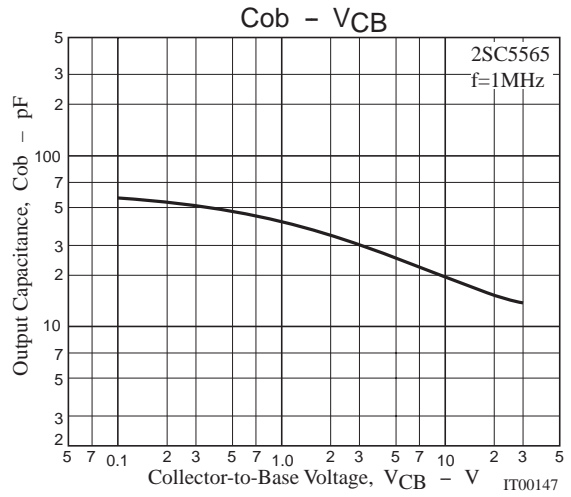
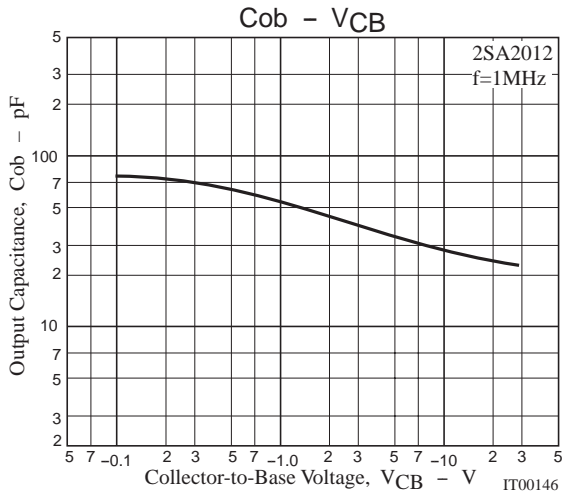
Switching Time Test Circuit



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